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BGU7032

1 GHz wideband low-noise amplifier with bypass Rev. 2 — 14 September 2010 Pro

Product data sheet

Product profile 1.

1.1 General description

The BGU7032 MMIC is a wideband amplifier with bypass mode. It is designed specifically for high linearity, low-noise applications over a frequency range of 40 MHz to 1 GHz. It is especially suited to Set-Top Box applications.

The LNA is housed in a 6-pin SOT363 plastic SMD package.

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features and benefits

- Internally biased
- Programmable between G_p = 10 dB and bypass
- Flat gain between 40 MHz and 1 GHz
- Noise figure of 4.5 dB
- High linearity with an IP3_O of 29 dBm
- \blacksquare 75 Ω input and output impedance
- Power-down during bypass mode
- Bypass mode current consumption < 5 mA
- ESD protection > 2 kV Human Body Model (HBM) on all pins

1.3 Applications

- Terrestrial and cable Set-Top Boxes (STB)
- Silicon and "Can" tuners
- Personal and Digital Video Recorders (PVR and DVR)
- Home networking and in-house signal distribution



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1.4 Quick reference data

Table 1. Quick reference data

 T_{amb} = 25 °C; typical values at V_{CC} = 5 V; Z_S = Z_L = 75 Ω ; R_{bias} = 43 Ω ; 40 MHz \leq $f_1 \leq$ 1000 MHz.

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|----------------------|---------------------------------------|-----------------------------------|------------|------|-----|------|------|
| V_{CC} | supply voltage | RF input AC coupled | | 4.75 | 5.0 | 5.25 | V |
| I _{CC(tot)} | total supply current | G _p = 10 dB mode | [1] | - | 43 | - | mA |
| | | bypass mode | [1] | - | 4 | - | mA |
| T _{amb} | ambient temperature | | | -10 | - | +70 | °C |
| NF | noise figure | G _p = 10 dB mode | <u>[1]</u> | - | 4.5 | - | dB |
| | | bypass mode | <u>[1]</u> | - | 2.5 | - | dB |
| P _{L(1dB)} | output power at 1 dB gain compression | 1 GHz; $G_p = 10 \text{ dB}$ mode | <u>[1]</u> | - | 14 | - | dBm |
| IP3 _O | output third-order intercept point | G _p = 10 dB mode | [1][2] | - | 29 | - | dBm |
| | | | | | | | |

^[1] Mode depends on setting of V_{CTRL} ; see <u>Table 8</u>.

2. Pinning information

Table 2. Pinning

| Pin | Description | Simplified outline | Graphic symbol |
|-----|-----------------|--------------------|--|
| 1 | RF_OUT | 0.00 | |
| 2 | V _{CC} | 6 5 4 | $\begin{pmatrix} 3 & 2 \\ 1 & 1 \end{pmatrix}$ |
| 3 | n.c. | | 6— |
| 4 | CTRL | 0 | |
| 5 | GND | □1 □2 □3 | 5 4 sym141 |
| 6 | RF_IN | | 9, |

3. Ordering information

Table 3. Ordering information

| Type number | Package | | | | | |
|-------------|---------|--|---------|--|--|--|
| | Name | Description | Version | | | |
| BGU7032 | - | plastic surface-mounted package; 6 leads | SOT363 | | | |

4. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| BGU7032 | SD% |

Note: % character indicates the location of production.

^[2] The fundamental frequency (f_1) is 1000 MHz. The intermodulation product (IM3) is $2 \times f_2 - f_1$, where $f_2 = f_1 \pm 1$ MHz. Input power $P_i = -10$ dBm.

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5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|-----------------------|---------------------------------|--|-----|------|----------|------|
| V_{CC} | supply voltage | RF input AC coupled | | -0.6 | 5.25 | V |
| $V_{\text{ctrl}(Gp)}$ | power gain control voltage | pin CTRL | [1] | 0 | V_{CC} | V |
| $I_{CC(tot)}$ | total supply current | | | - | 60 | mΑ |
| P _{tot} | total power dissipation | T _{sp} ≤ 100 °C | [2] | - | 250 | mW |
| Pi | input power | single tone | | - | 10 | dBm |
| T _{stg} | storage temperature | | | -65 | +150 | °C |
| Tj | junction temperature | | | - | 150 | °C |
| T _{amb} | ambient temperature | | | -10 | +70 | °C |
| V _{ESD} | electrostatic discharge voltage | Human Body Model (HBM); according to JEDEC standard 22-A114E | | 2 | - | kV |

^[1] $V_{ctrl(Gp)}$ must not exceed V_{CC} ; I_{CTRL} must be limited to 5 mA (maximum).

Remark: $V_{ctrl(Gp)}$ must not exceed V_{CC} ; I_{CTRL} must be limited to a maximum of 5 mA.

6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Тур | Unit |
|----------------|--|------------|-----|------|
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point | | 240 | K/W |

7. Characteristics

Table 7. Characteristics

 T_{amb} = 25 °C; typical values at V_{CC} = 5 V; Z_S = Z_L = 75 Ω ; R_{bias} = 43 Ω ; 40 MHz \leq $f_1 \leq$ 1000 MHz.

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|------------------|--------------------------------|-----------------------------|-----|------|------|------|------|
| V_{CC} | supply voltage | RF input AC coupled | | 4.75 | 5.0 | 5.25 | V |
| $I_{CC(tot)}$ | total supply current | $G_p = 10 \text{ dB mode}$ | [1] | - | 43 | - | mA |
| | | bypass mode | [1] | - | 4 | - | mA |
| $ s_{21} ^2$ | insertion power gain | G _p = 10 dB mode | [1] | - | 10 | - | dB |
| | | bypass mode | [1] | - | -2 | - | dB |
| SL _{sl} | slope straight line | | | - | -1 | - | dB |
| FL | flatness of frequency response | | | - | -0.2 | - | dB |
| NF | noise figure | G _p = 10 dB mode | [1] | - | 4.5 | - | dB |
| | | bypass mode | [1] | - | 2.5 | - | dB |
| RLin | input return loss | G _p = 10 dB mode | [1] | - | 18 | - | dB |
| | | bypass mode | [1] | - | 8 | - | dB |

^[2] T_{sp} is the temperature at the solder point of the ground lead.

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 Table 7.
 Characteristics ...continued

 T_{amb} = 25 °C; typical values at V_{CC} = 5 V; Z_S = Z_L = 75 Ω ; R_{bias} = 43 Ω ; 40 MHz \leq $f_1 \leq$ 1000 MHz.

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|---------------------|---------------------------------------|-----------------------------------|--------|-----|-----|-----|------|
| RLout | output return loss | $G_p = 10 \text{ dB mode}$ | [1] | - | 12 | - | dB |
| | | bypass mode | [1] | - | 8 | - | dB |
| P _{L(1dB)} | output power at 1 dB gain compression | 1 GHz; $G_p = 10 \text{ dB}$ mode | [1] | - | 14 | - | dBm |
| IP3 _O | output third-order intercept point | G _p = 10 dB mode | [1][2] | - | 29 | - | dBm |
| | | bypass mode | [1][2] | - | 29 | - | dBm |

^[1] Mode depends on setting of $V_{ctrl(Gp)}$ (V_{CTRL}); see <u>Table 8</u>.

Table 8. Gain selection (pin CTRL)

-10 °C \leq $T_{amb} \leq$ +70 °C; recommended power-up condition: V_{CTRL} = logic 0 or < 0.7 V.

| V _{ctrl(Gp)} (V _{CTRL}) (V) | Mode |
|--|-----------------------|
| ≤ 0.7 | bypass |
| ≥ 4.3 | $G_p = 10 \text{ dB}$ |

Remark: $V_{ctrl(Gp)}$ must not exceed V_{CC} ; I_{CTRL} must be limited to a maximum of 5 mA.

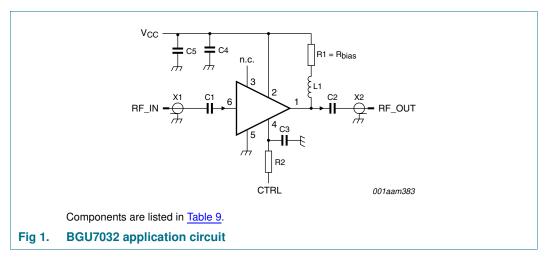
^[2] The fundamental frequency (f_1) is 1000 MHz. The intermodulation product (IM3) is $2 \times f_2 - f_1$, where $f_2 = f_1 \pm 1$ MHz. Input power $P_i = -10$ dBm.

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8. Application information

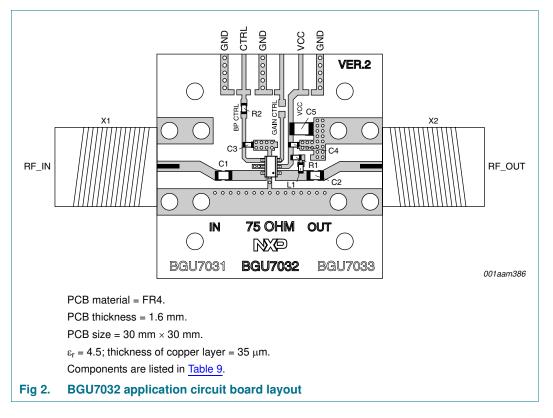
Other applications are possible. Please contact your local sales representative for more information. Application notes are available on the NXP website.

8.1 Application circuit



All control and supply lines must be decoupled properly. The decoupling capacitors must be placed as close to the device as possible.

8.2 Application circuit board layout



1 GHz wideband low-noise amplifier with bypass

Table 9.List of componentsSee Figure 1 and Figure 2.

| Component | Description | Value | | Remarks | Function |
|-----------|-------------------|------------------------|-----|---|------------------|
| C1, C2 | capacitor | 10 nF | | | DC blocking |
| C3, C4 | capacitor | 10 nF | | | decoupling |
| C5 | capacitor | 10 μF | | | decoupling |
| L1 | chip ferrite bead | $1.5~\mathrm{k}\Omega$ | [1] | Murata BLM18HE152SN1DF | RF choke |
| R1 | resistor | 43 Ω | [1] | R _{bias} | bias setting |
| R2 | resistor | $1.8~\mathrm{k}\Omega$ | | | current limiting |
| X1, X2 | connector | 75 Ω | | F-connector, edge mount PCB reflow type, Bomar 861V509ERG | input/output |

^[1] L1 and R1 must have a power rating of 0.1 W or higher.

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9. Package outline

Plastic surface-mounted package; 6 leads

SOT363

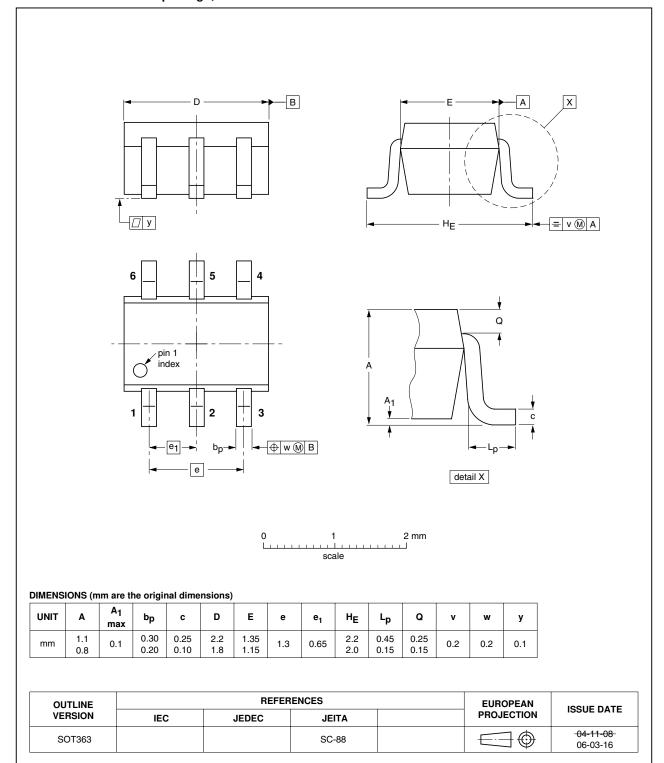


Fig 3. Package outline SOT363

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10. Abbreviations

Table 10. Abbreviations

| Acronym | Description |
|---------|---|
| AC | Alternating Current |
| DC | Direct Current |
| LNA | Low-Noise Amplifier |
| MMIC | Monolithic Microwave Integrated Circuit |
| PCB | Printed-Circuit Board |
| RF | Radio Frequency |
| SMD | Surface-Mounted Device |

11. Revision history

Table 11. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
|---|--------------|------------------------|---------------|-------------|--|--|
| BGU7032 v.2 | 20100914 | Product data sheet | - | BGU7032 v.1 | | |
| Modifications: • The status of this data sheet has been changed to Product data sheet. | | | | | | |
| BGU7032 v.1 | 20100817 | Preliminary data sheet | - | - | | |

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12. Legal information

12.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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1 GHz wideband low-noise amplifier with bypass

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